

# Radar Pulsed Power Transistor 110W, 2.7-2.9 GHz, 100µs Pulse, 10% Duty

M/A-COM Products Released, 29 Jun 07

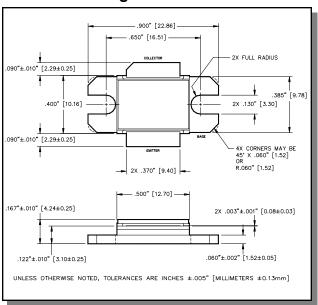
#### **Features**

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- · High efficiency inter-digitized geometry
- · Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

## Absolute Maximum Ratings at 25°C

| Parameter                 | Symbol           | Rating      | Units |
|---------------------------|------------------|-------------|-------|
| Collector-Emitter Voltage | $V_{CES}$        | 63          | V     |
| Emitter-Base Voltage      | $V_{EBO}$        | 3.0         | V     |
| Collector Current (Peak)  | Ic               | 8.0         | Α     |
| Power Dissipation @ +25°C | P <sub>TOT</sub> | 330         | W     |
| Storage Temperature       | $T_{STG}$        | -65 to +200 | °C    |
| Junction Temperature      | $T_J$            | 200         | °C    |

#### **Outline Drawing**



# Electrical Specifications: $T_C = 25 \pm 5^{\circ}C$ (Room Ambient)

| Parameter                           | Test Conditions       | Frequency             | Symbol              | Min | Max   | Units |
|-------------------------------------|-----------------------|-----------------------|---------------------|-----|-------|-------|
| Collector-Emitter Breakdown Voltage | I <sub>C</sub> = 50mA |                       | BV <sub>CES</sub>   | 63  | -     | V     |
| Collector-Emitter Leakage Current   | V <sub>CE</sub> = 36V |                       | I <sub>CES</sub>    | -   | 7.5   | mA    |
| Thermal Resistance                  | Vcc = 36V, Pin = 23W  | F = 2.7, 2.8, 2.9 GHz | R <sub>TH(JC)</sub> | -   | 0.3   | °C/W  |
| Output Power                        | Vcc = 36V, Pin = 23W  | F = 2.7, 2.8, 2.9 GHz | P <sub>OUT</sub>    | 110 | -     | W     |
| Power Gain                          | Vcc = 36V, Pin = 23W  | F = 2.7, 2.8, 2.9 GHz | G <sub>P</sub>      | 6.8 | -     | dB    |
| Collector Efficiency                | Vcc = 36V, Pin = 23W  | F = 2.7, 2.8, 2.9 GHz | ης                  | 35  | -     | %     |
| Input Return Loss                   | Vcc = 36V, Pin = 23W  | F = 2.7, 2.8, 2.9 GHz | RL                  | -   | -6    | dB    |
| Load Mismatch Tolerance             | Vcc = 36V, Pin = 23W  | F = 2.7, 2.8, 2.9 GHz | VSWR-T              | -   | 2:1   | -     |
| Load Mismatch Stability             | Vcc = 36V, Pin = 23W  | F = 2.7, 2.8, 2.9 GHz | VSWR-S              | -   | 1.5:1 | -     |

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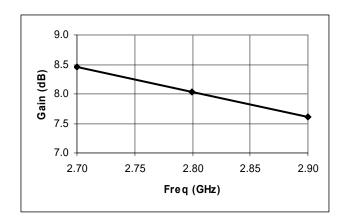


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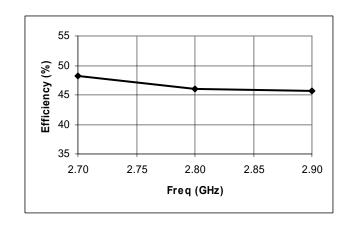
## **Typical RF Performance**

| Freq.<br>(GHz) | Pin<br>(W) | Pout<br>(W) | Gain<br>(dB) | Ic<br>(A) | Eff<br>(%) | RL<br>(dB) | VSWR-S<br>(1.5:1) | VSWR-T<br>(2:1) |
|----------------|------------|-------------|--------------|-----------|------------|------------|-------------------|-----------------|
| 2.7            | 23         | 162         | 8.46         | 9.31      | 48.2       | -23.9      | S                 | Р               |
| 2.8            | 23         | 146         | 8.03         | 8.82      | 46.0       | -16.6      | S                 | Р               |
| 2.9            | 23         | 133         | 7.60         | 8.07      | 45.6       | -13.8      | S                 | Р               |

## Gain vs. Frequency

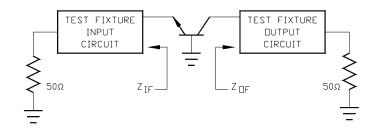


## Collector Efficiency vs. Frequency



### **RF Test Fixture Impedance**

| F (GHz) | Z <sub>IF</sub> (Ω) | Z <sub>OF</sub> (Ω) |
|---------|---------------------|---------------------|
| 2.7     | 4.3 - j7.0          | 2.6 - j3.9          |
| 2.8     | 4.4 - j6.4          | 2.8 - j3.5          |
| 2.9     | 4.6 - j5.8          | 2.9 - j3.1          |



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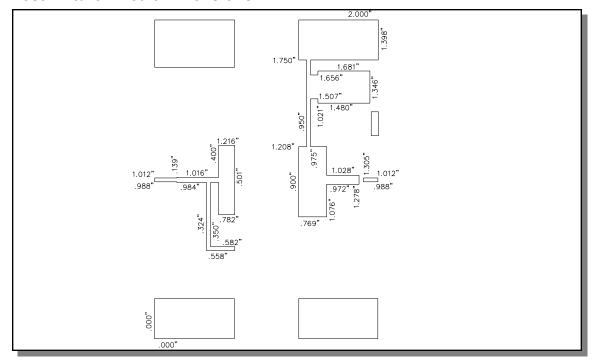
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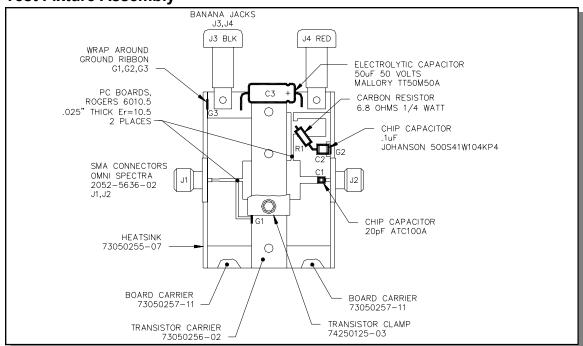


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#### **Test Fixture Circuit Dimensions**



### **Test Fixture Assembly**



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